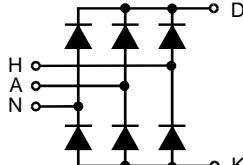


Three Phase Rectifier Bridge

$I_{dAV} = 28 \text{ A}$
 $V_{RRM} = 600-1200 \text{ V}$

Preliminary data

| V_{RSM} | V_{RRM} | Type |
|-----------|-----------|--------------|
| V | V | |
| 700 | 600 | VUO 28-06N07 |
| 900 | 800 | VUO 28-08N07 |
| 1300 | 1200 | VUO 28-12N07 |



| Symbol | Test Conditions | Maximum Ratings | | |
|---------------|---|-----------------|----------------------|--|
| I_{dAV} ① | $T_c = 100^\circ\text{C}$, module | 28 | A | |
| I_{FSM} | $T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine | 100 | A | |
| | $T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine | 85 | A | |
| I^2t | $T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine | 50 | A^2s | |
| | $T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine | 36 | A^2s | |
| | | 33 | A^2s | |
| T_{VJ} | | -40...+150 | $^\circ\text{C}$ | |
| T_{VJM} | | 150 | $^\circ\text{C}$ | |
| T_{stg} | | -40...+125 | $^\circ\text{C}$ | |
| V_{ISOL} | 50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$ | 2500 | V~ | |
| | | 3000 | V~ | |
| M_d | Mounting torque (M4) | 1.5 - 2 | Nm | |
| | | 14 - 18 | lb.in. | |
| Weight | typ. | 18 | g | |

| Symbol | Test Conditions | Characteristic Values | | |
|------------|---|-----------------------|-------------|-----------------------|
| I_R | $V_R = V_{RRM}$; $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$; $T_{VJ} = T_{VJM}$ | \leq \leq | 0.3 5 | mA |
| V_F | $I_F = 7 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$ | \leq | 1.12 | V |
| V_{TO} | For power-loss calculations only | | 0.8 40 | V $\text{m}\Omega$ |
| r_T | | | | |
| R_{thJC} | per diode; DC current per module | | 2.3 0.39 | K/W |
| R_{thJH} | per diode, DC current per module | | 2.8 0.47 | K/W |
| d_s | Creeping distance on surface | | 11.2 | mm |
| d_A | Creepage distance in air | | 9.7 | mm |
| a | Max. allowable acceleration | | 50 | m/s^2 |

Data according to IEC 60747 refer to a single diode unless otherwise stated
① for resistive load at bridge output.

IXYS reserves the right to change limits, test conditions and dimensions.

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Features

- Package with DCB ceramic base plate
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

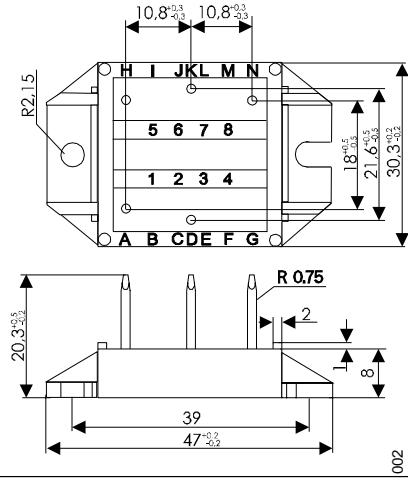
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight

Dimensions in mm (1 mm = 0.0394")



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